

MOSFETs Silicon N-Channel MOS

# **SSM6N815R**

## 1. Applications

· Power Management Switches

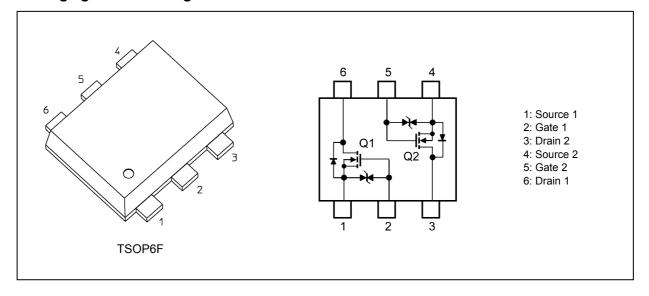
#### 2. Features

- (1) 4.0 V drive
- (2) Low drain-source on-resistance
  - $: R_{DS(ON)} = 115 \text{ m}\Omega \text{ (typ.) } (@V_{GS} = 4.0 \text{ V})$

 $R_{\rm DS(ON)} = 101 \ {\rm m}\Omega \ ({\rm typ.}) \ (@V_{\rm GS} = 4.5 \ {\rm V})$ 

 $R_{\mathrm{DS(ON)}} = 84~\mathrm{m}\Omega$  (typ.) (@ $V_{\mathrm{GS}} = 10~\mathrm{V}$ )

#### 3. Packaging and Pin Assignment



Start of commercial production

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#### Absolute Maximum Ratings (Note) (Unless otherwise specified, T<sub>a</sub> = 25 °C) (Q1,Q2 Common)

Characteristics	Symbol	Rating	Unit		
Drain-source voltage			$V_{DSS}$	100	V
Gate-source voltage			$V_{GSS}$	±20	
Drain current (DC)		(Note 1)	I <sub>D</sub>	2	Α
Drain current (pulsed)		(Note 1), (Note 2)	I <sub>DP</sub>	4	
Power dissipation		(Note 3)	$P_D$	1.4	W
Power dissipation	(t ≤ 10 s)	(Note 3)		1.8	
Single-pulse avalanche energy		(Note 4)	E <sub>AS</sub>	10.1	mJ
Avalanche current			I <sub>AR</sub>	2	Α
Channel temperature			T <sub>ch</sub>	150	°C
Storage temperature			T <sub>stg</sub>	-55 to 150	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

- Note 1: Ensure that the channel temperature does not exceed 150°C.
- Note 2: Pulse width (PW)  $\leq$  10 s, duty  $\leq$  1%
- Note 3: Device mounted on an FR4 board. (PD for the entire IC) (FR4, 25.4 mm  $\times$  25.4 mm  $\times$  1.6 mm, Cu pad: 645 mm<sup>2</sup>)
- Note 4:  $V_{DD}$  = 25 V, Tch = 25 °C (Initial state), L = 1 mH, R<sub>G</sub> = 25  $\Omega$

Note: The MOSFETs in this device are sensitive to electrostatic discharge. When handling this device, the worktables, operators, soldering irons and other objects should be protected against anti-static discharge.

Note: The channel-to-ambient thermal resistance,  $R_{th(ch-a)}$ , and the drain power dissipation,  $P_D$ , vary according to the board material, board area, board thickness and pad area. When using this device, be sure to take heat dissipation fully into account.



#### 5. Electrical Characteristics

### 5.1. Static Characteristics (Unless otherwise specified, T<sub>a</sub> = 25 °C) (Q1,Q2 Common)

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current		I <sub>GSS</sub>	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 16 \text{ V}$	_	_	±10	μА
Drain cut-off current		I <sub>DSS</sub>	V <sub>DS</sub> = 100 V, V <sub>GS</sub> = 0 V	_	_	1	
Drain-source breakdown voltage		V <sub>(BR)DSS</sub>	I <sub>D</sub> = 10 mA, V <sub>GS</sub> = 0 V	100	_	_	V
Drain-source breakdown voltage	(Note 1)	V <sub>(BR)DSX</sub>	I <sub>D</sub> = 10 mA, V <sub>GS</sub> = -20 V	80	_	_	
Gate threshold voltage	(Note 2)	V <sub>th</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 0.1 mA	1.5	_	2.5	
Drain-source on-resistance	(Note 3)	R <sub>DS(ON)</sub>	I <sub>D</sub> = 1 A, V <sub>GS</sub> = 4.0 V	_	115	180	mΩ
			I <sub>D</sub> = 2 A, V <sub>GS</sub> = 4.5 V	_	101	142	
			I <sub>D</sub> = 2 A, V <sub>GS</sub> = 10 V	_	84	103	
Forward transfer admittance	(Note 3)	Y <sub>fs</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 2 A	_	4.8	_	S

Note 1: If a reverse bias is applied between gate and source, this device enters  $V_{(BR)DSX}$  mode. Note that the drain-source breakdown voltage is lowered in this mode.

Note 2: Let  $V_{th}$  be the voltage applied between gate and source that causes the drain current ( $I_D$ ) to below (0.1 mA for this device). Then, for normal switching operation,  $V_{GS(ON)}$  must be higher than  $V_{th}$ , and  $V_{GS(OFF)}$  must be lower than  $V_{th}$ . This relationship can be expressed as:  $V_{GS(OFF)} < V_{th} < V_{GS(ON)}$ .

Take this into consideration when using the device.

Note 3: Pulse measurement.

#### 5.2. Dynamic Characteristics (Unless otherwise specified, T<sub>a</sub> = 25 °C) (Q1,Q2 Common)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Input capacitance	C <sub>iss</sub>	V <sub>DS</sub> = 15 V , V <sub>GS</sub> = 0 V,	-	290	_	pF
Reverse transfer capacitance	C <sub>rss</sub>	f = 1 MHz	_	16	_	
Output capacitance	Coss		1	108		
Switching time (turn-on time)	t <sub>on</sub>	$V_{DD} = 30 \text{ V}, I_{D} = 1 \text{ A},$ $V_{GS} = 0 \text{ to } 4.5 \text{ V}, R_{G} = 50 \Omega$		7.5		ns
Switching time (turn-off time)	t <sub>off</sub>	Duty $\leq$ 1 %, Input: $t_r$ , $t_f$ < 5 ns Ground source, See Chapter 5.3		21	_	

#### 5.3. Switching Time Test Circuit

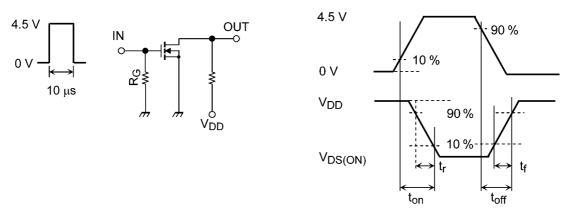


Fig. 5.3.1 Switching Time Test Circuit

Fig. 5.3.2 Input Waveform/Output Waveform

# 5.4. Gate Charge Characteristics (Unless otherwise specified, T<sub>a</sub> = 25 °C) (Q1,Q2 Common)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Total gate charge (gate-source plus gate-drain)		$V_{DD} = 50 \text{ V}, I_D = 2 \text{ A},$	_	3.1		nC
Gate-source charge 1	Q <sub>gs1</sub>	V <sub>GS</sub> = 4.5 V	_	1.1		
Gate-drain charge	Q <sub>gd</sub>		_	1.5		

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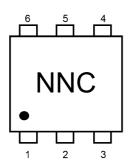


# 5.5. Source-Drain Characteristics (Unless otherwise specified, $T_a$ = 25 °C) (Q1,Q2 Common)

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Diode forward voltage	(Note 1)	$V_{DSF}$	$I_D = -2 A, V_{GS} = 0 V$	_	-0.9	-1.5	V

Note 1: Pulse measurement.

# 6. Marking





# 7. Characteristics Curves (Q1,Q2 Common) (Note)

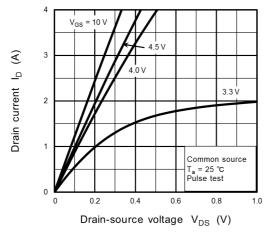


Fig. 7.1 I<sub>D</sub> - V<sub>DS</sub>

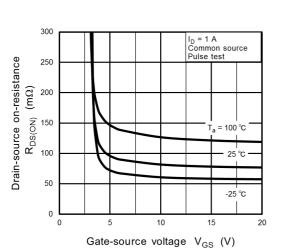


Fig. 7.3 R<sub>DS(ON)</sub> - V<sub>GS</sub>

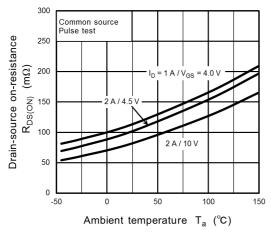


Fig. 7.5 R<sub>DS(ON)</sub> - T<sub>a</sub>

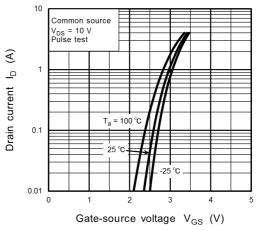


Fig. 7.2 I<sub>D</sub> - V<sub>GS</sub>

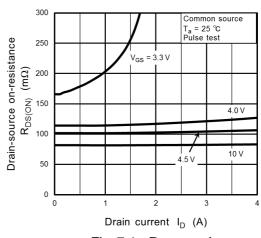


Fig. 7.4 R<sub>DS(ON)</sub> - I<sub>D</sub>

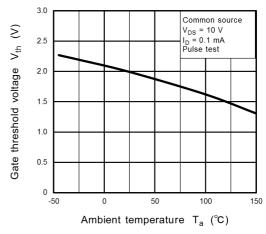


Fig. 7.6 V<sub>th</sub> - T<sub>a</sub>

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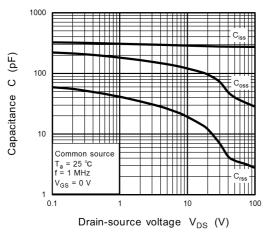


Fig. 7.7 C - V<sub>DS</sub>

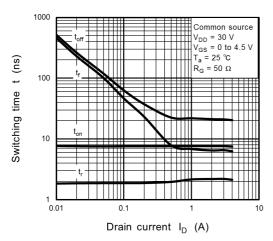


Fig. 7.9 t - I<sub>D</sub>

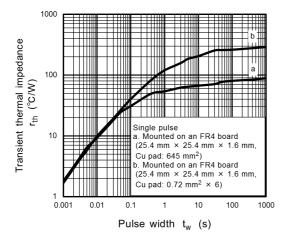


Fig. 7.11 rth - tw

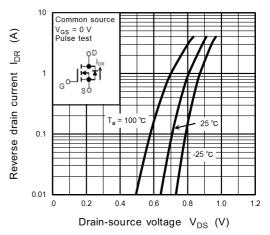


Fig. 7.8 IDR - VDS

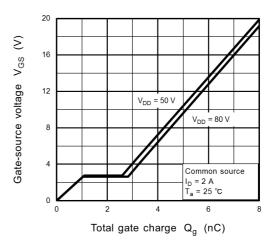


Fig. 7.10 Dynamic Input Characteristics

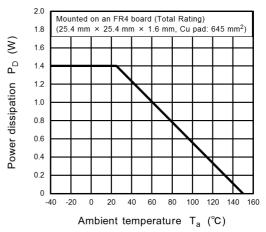


Fig. 7.12 P<sub>D</sub> - T<sub>a</sub>

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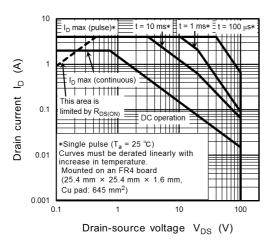


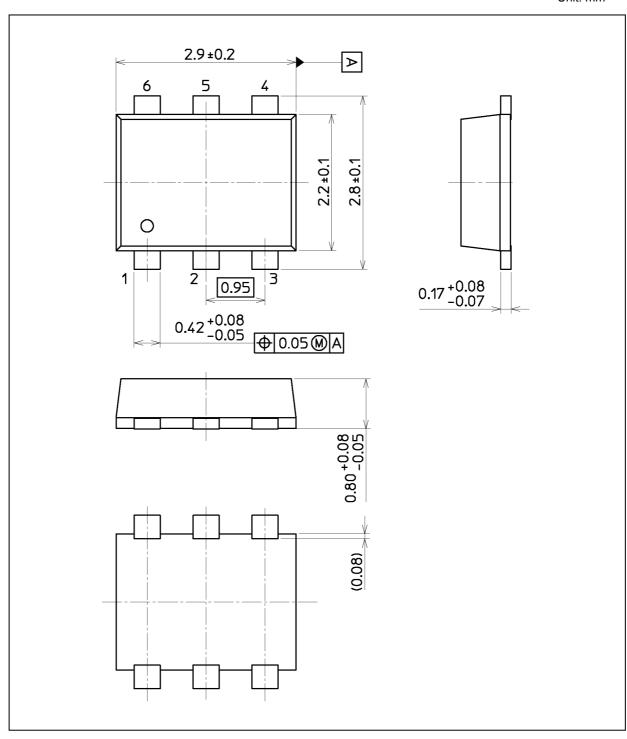
Fig. 7.13 Safe Operationg Area

Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



# **Package Dimensions**

Unit: mm



Weight: 0.016 g (typ.)

	Package Name(s)
Nickname: TSOP6F	



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